TI Designs Isolated IGBT Gate-Drive Fly-Buck™ Power Supply with 4 Outputs

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Design Features

- Isolated power supply for IGBT gate driving implemented with Fly-Buck™
- Supports 2 IGBT gate drivers in half-bridge configuration
- Fly-Buck™ topology provides easy-to-design multi-output isolated power supply solution with primary side regulation
- Four isolated voltage rails: 2x(+16V, -9V)
- Operates with unregulated 24V+/-20% input
- Output Power: 2.5W per IGBT driver, each isolated output rated for 100mA,
- Can support driving IGBT up to 200A/1200V
- Isolation: 5000VAC from primary to secondary

Featured Applications

- Variable Speed AC drives
- Industrial Inverters / Solar Inverters
- UPS Systems
- Servo Drives
- IGBT based HVDC systems





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1 System Description

The Insulated Gate Bipolar Transistor (IGBT) is widely used in high power inverters and AC motor drive applications. The IGBT gate drives require a steady and robust isolated power supply for the reliable IGBT switching. This reference design provides isolated positive and negative bias voltage rails required for the IGBT gate drivers using the Fly-Buck topology. The Fly-Buck converter circuit can be deemed a combination of a buck converter on the primary side and a flyback-like secondary side. The isolated outputs are generated through the coupled windings of the transformer. The Fly-Buck has primary side regulation, and can achieve good cross regulation without opto-coupler feedback or auxiliary winding. This reference design is implemented with LM5017, the wide Vin constant on-time (COT) synchronous buck regulator. It is capable of operating from a loosely regulated 24Vdc input, and generates two pair of +16V and -9V, 100mA isolated outputs, suitable for powering two IGBT gate drivers.

The +16V voltage is to power the driver IC/circuit and provide the bias for IGBT turn on, whilst the -9V is to provide a negative bias for IGBT turn off. There are two sets of the positive/negative outputs isolated from each other, and it can support driving 2 IGBTs in the half bridge configuration. For the three phase inverter topology, used in variable-frequency drive in AC motor, the typical gate driver application block diagram is shown in **Figure 1-1** below. Note that each phase uses a high-side and a low-side IGBT switch to apply positive and negative high-voltage DC pulses to the motor coils in an alternating mode. A high power IGBT requires isolated gate drivers to control their operations. Each IGBT is driven by a single gate driver that is isolated from the high-voltage output to the low-voltage control inputs. Also, as the emitter of the top IGBT floats, it necessitates the using of isolated gate driver.



Figure 1-1 3-phase Inverter with Isolated Gate-drive

1.1 Requirements of an IGBT Gate Drive Supply

The IGBT is a minority-carrier device with high input impedance and large bipolar current-carrying capability. When turned on, IGBTs and MOSFETs behave in the similar way, with similar current rise and voltage fall times. In order to reduce the power losses, the gate voltage of the IGBTs are pulled to a much higher level than the gate-threshold voltage when turning on. Typically, +15V to +18V are applied at the gate driver.

At turn-off, however, the switched current waveform in the IGBT is different from the MOSFET. At the end of the switching event, the IGBT has a tail current due to the minority carriers still trapped in the base of

the bipolar section of the IGBT. Unlike a bipolar transistor, it is not possible to extract these carriers to speed up switching, as there is no external connection to the base section, and so the device remains turned on until the carriers recombine. This tail current increases the turn-off loss and requires an increase in the dead time between the conduction of two devices in a half-bridge circuit. For the turn-off bias, usually a negtive voltage supply is required to prevent the high voltage swing induced false turn-on. In general, the negative voltage is set to -5V to -15V.

The traditional isolated switched power topologies such as push-pull, flyback and forward converters are widely used for the gate drive bias supply. The output regulation of these solutions is often relied on either open-loop fixed duty cycle switching or auxilliary winding feedback closed-loop control. The disadvantages of using open-loop control are that the line and load transient response is poor, and it requires the input DC voltage to be tightly regulated, or needs post-regulation LDOs. For the auxilliary winding feedback method, the cross regulation between multiple outputs is not optimal. However, the Fly-Buck topolgy has the inherent primary side regulation feature, and can achieve isolated output regulation effortlessly. The cross regulation performance is better overall between outputs.

2 Fly-Buck Converter Operation

The primary objective of this design is to provide a high performance, cost effective and easy-to-design isolated power supply solution for IGBT gate drive bias power. The Fly-Buck is basically a buck regulator with couple windings added to the inductor. The coupled windings can generate isolated outputs. It looks like a combination of buck and flyback converter, and, thus, it is called Fly-buck (**Figure 2-1**). The operation on the primary side is similar to the buck, while the secondary side output is clamped by the primary output.



Figure 2-2 the Fly-Buck in On- and Off- Time



The Fly-Buck operation in a switching cycle can be divided into on time and off time (**Figure 2-2**). During T_{ON} , the rectifier diode is in reverse bias and thus the secondary side is cut off from the primary. The primary side operates like in a buck regulator: the transformer primary current rise linearly. The primary output voltage is $V_{PRI} = D \cdot V_{IN}$. During T_{OFF} , the diode is forward biased and conducts. The current can flow in the primary and secondary side at the same time. Yet the magnetizing current in the transformer is still in the triangle waveform, which can be calculated as the combination of the primary and secondary winding current, $i_m = i_{PRI} + Ni_{SEC}$. The secondary output voltage is clamped by the primary side output, $V_{SEC} = N \cdot V_{PRI}$. The steady-state operation waveforms of a Fly-Buck are shown in **Figure 2-3**.



Figure 2-3 the Fly-Buck Operation Waveforms

From the above analysis, the magnetizing current ripple can be derived as

$$\Delta i_m = \frac{V_{PRI}}{L_{PRI}} \frac{1 - D}{F_{SW}}$$

where L_{PRI} is the primary winding inductance, $D = T_{ON}/(T_{ON} + T_{OFF})$ is the duty cycle, and F_{SW} is the switching frequency. The peak current of the primary side can be thus calculated as

$$I_{m(PEAK)} = I_m + \frac{1}{2}\Delta i_m = I_{OPRI} + N I_{OSEC} + \frac{1}{2}\Delta i_m$$

where I_{OPRI} is the average primary output current, and I_{OSEC} is the average secondary output current. If multiple outputs are involved, each secondary output needs to be converted to the primary side by multiplying the corresponding turns ratio, and the above equation can still be applied.

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3 Fly-Buck Design Procedure

Here below is the design procedure of the Fly-Buck power supply for the IGBT gate driver bias.

3.1 Design Specification

The system-level requirements for this design are:

- 1. The isolated positive and negative rails should be +16V and -9V to power the isolated gate driver.
- 2. Continuous output power of 2.5W to drive each IGBT.

Input: 24V ± 20%

Output: Isolated 2×(+16V@100mA; -9V@100mA)

Frequency: 350kHz

3.2 Circuit Parameter Design

1. Determine the primary-side output:

The primary-side, non-isolated output is set to 10.3V for several considerations. First, it is below the minimum 19V V_{IN} , and the theoretical duty cycle will vary from 34 to 54 percent at the full V_{IN} range, which is considered a balanced duty cycle. Optimally, it is favorable to have the Fly-Buck switching duty cycle below 50%. Because the Fly-Buck utilizes the duty off-time to transfer energy to the secondary side, and the high duty cycle will choke the current flow and affect the regulation. For this design, some tradeoff has to be made to accommodate the transformer turns ratio and the current limit of the LM5017. Additionally, the LM5017 can utilize this 10.3V to supply its own V_{CC} bypassing the internal LDO, which is more efficient than powering V_{CC} from Vin directly.

2. Determine the transformer turns ratio:

Based on the primary output to the isolated outputs ratio, the sec-to-pri turns ratio for the -9V output is 1:1.08, which is 1.62:1 for the +16V output. These turns ratios are rounded up to integer numbers for the convenience of the winding count. The +16V windings can share the ground pin with the -9V output, as long as the isolation between these two outputs is not required. This helps to reduce the size and save the pin count. The transformer winding configuration is shown in **Figure 3-1**.



Figure 3-1 Transformer winding configuration



3. Choose the inductance and switching frequency:

After knowing the turns ratio, the total average current in the primary winding can be calculated, which gives 0.51A. We choose a 60uH primary inductance. With the 350 kHz switching frequency, the peak current is thus calculated as 0.67A at maximum VIN = 30V, which is below the 0.7A peak-current limit.

4. Design the ripple injection network:

The COT control requires minimum external part count to make the IC switching stable. The ripple injection network is a RC network (shown in **Figure 3-2**) that generates a voltage ripple and has it injected to the FB pin.



Figure 3-2 the Ripple Injection Network

The design principle and calculation tools of the ripple injection network can be found on the <u>LM5017</u> product page on ti.com. The following RC parameters are set: Rr=40.2 k Ω , Cr=10 nF and Cac=1 nF.



3.3 Transformer Selection

Based on the design consideration, the transformer (part number: 750314624) is designed by Wurth Midcom Electronics. The transformer's winding configuration is shown in **Figure 3-1**. The isolation rating is as follows:

- 5000VAC, 1 minute tested between primary to secondary. Designed with reinforced insualtion from primary to secondary with 8mm of creepage and clearance distance
- 1875VAC, 1 minute tested between secondaries. Designed with basic insulation from secondary to secondary with 5.5mm of creepage and clearance distance

3.4 Schematic

The below **Figure 3-3** is the schematic of the 4-output Fly-Buck design.



Gate Drive Bias

Figure 3-3 Fly-buck schematic

4 **Power Supply Test Results**

In this section, the performance of reference board as an isolated power supplied is tested.

4.1 Efficiency and Regulation

The efficiency is measured with all the four output loaded with the same load current. The peak efficiency is around 84% as shown in **Figure 4-1**.







The regulation data is captured at different Vin values as well as different load as shown in **Figure 4-2** and **Figure 4-3** below. Due to the symmetric winding and circuit structure, the two pair of isolated output performance reflects and mirrors to each other. Thus, the results of only one +16V/-9V outputs are shown. From the result, it can be seen that the worst case happens at minimum Vin and heavy load, where the largest variation of the output is still within 7%.





Figure 4-2 +16V and -9V Regulation at full load and no load over different Vin



Figure 4-3 +16V and -9V Regulation at 19V and 24V Vin over different load

4.2 Start Up

The start-up of the power supply is tested under nominal 24V working voltage, and all four outputs were set at 100mA load. The below waveform shows the ramp-up of the isolated outputs, where Ch1 - Vin, Ch2 – +16V output, Ch3 – -9V output.



Figure 4-4 Start up at nominal Vin

4.3 Switching Waveforms

The stable switching of the Fly-Buck converter is examined at the switch node on the primary side and also checked at the secondary rectifier diodes to make sure the voltage spikes across are within the voltage rating. From the below test waveforms, we can find that the switching frequency remains relatively stable around 350kHz and the diode voltage stress is under the 100V rating with margin.

1. Test condition: The input voltage was set at 24V, and all four outputs were set at 100mA load. Ch1 – Vsw (switch node voltage)





Figure 4-5 Switching node waveform at 100mA load

2. Test condition: The input voltage was set at 24V, and all four outputs were set at no load. Ch1 – Vsw (switch node voltage).



Figure 4-6 Switching node waveform at no load

3. Test condition: The input voltage was set at 30V, and all four outputs were set at 100mA load. Ch1 – Vd5 (+16V output diode voltage stress from cathode (-) to anode (+), 100V rating diode)





Figure 4-7 +16V output diode voltage waveform at highest Vin at full load

4. Test condition: The input voltage was set at 30V, and all four outputs were set at 100mA load. Ch1 – Vd2 (-9V output diode voltage stress from cathode (-) to anode (+), 100V rating diode)



Figure 4-8 +16V output diode voltage waveform at highest Vin at full load

4.4 Load Transients

1. +16V Output Load Step

Test condition: Vin = 24V, +16V output load from 0A to 100mA, no load on other outputs. Ch1- +16V output (AC mode), Ch4- +16V output current





Figure 4-9 +16V output load transient

2. -9V Output Load Step

Test condition: Vin = 24V, -9V load from 0A to 100mA, no load on other outputs. Ch1- -9V output (AC mode), Ch4- -9V output current



Figure 4-10 -9V output load transient

4.5 *Output Voltage Ripples*

Test condition: The input voltage was set at 24V, and all four outputs were set at 100mA load. Ch1 - +16V output (AC coupled)





Figure 4-11 +16V output voltage ripple at full load



Figure 4-12 +16V output voltage ripple at full load



5 System Demo

To validate the reference design function in an IGBT system, we modified the C2000 High Voltage Single Phase Inverter Development Kit (TMDSHV1PHINVKIT) from TI to create a system demo. It is a full bridge DC/AC inverter with 4 IGBTs, and the input is 400V DC and the output is 110/220V AC selectable. The kit uses 4 driver card boards for driving the IGBT, which makes it convenient to replace them with the Fly-Buck solution. The original driver card design uses the opto-coupler gate driver and open-loop forward converter as the bias power. The 4-output Fly-Buck design can supply two IGBT drivers, and thus only two Fly-Buck driver cards are needed. The opto-coupler gate drivers are added to the design.

The two drivers are biased by the Fly-Buck isolated power supply design shown in **Figure 3-3**. The new driver card will take the PWM signals from the C2000 control card, and drive two IGBTs. The Fly-Buck driver card board is shown in **Figure 5-1**. The board is stretched longer than the actual component cover area, as the two connectors on the board are positioned to make compatible with the headers on the base board of the inverter kit.



Figure 5-1 Fly-Buck IGBT Driver Card Board

The inverter system with the plug-in Fly-Buck driver cards is shown in Figure 5-2.



Figure 5-2 Full Bridge Inverter with Fly-Buck IGBT Driver Cards



6 System Setup and Test

In this section, the demo setup guide is presented, and the system is tested.

6.1 System Setup

The Fly-Buck supply takes 24V input, but the inverter base board requires 15V as system power. Therefore, an external 24V DC supply is needed to supply the Fly-Buck driver card. The board configuration is as follows:

- 1. Configure jumpers on the inverter board: open JP1, JP2, JP3, short JP4, JP5, JP6
- 2. Plug in the Fly-Buck driver cards and the MCU control card to the base board as shown in Figure 5-2.
- 3. Connect external DC power supplies: tie +15V supply to JP1, tie +24V supply to JP2, and GND pins are accessible at connector CN5's pin 9, 10 as shown in **Figure 6-1**.
- 4. Connect the USB cable from the control card to the computer and turn on the +15V power supply



Figure 6-1 Inverter Board Auxiliary Power Connection

- 5. Use the Code Composer Studio (CCS) to load the inverter control program to the control card.
- 6. Check if the system is function correctly. The detailed program setting and the inverter kit information can be found in the Application Report, *High-Voltage Solar Inverter DC-AC Kit* (sprabr5).
- 7. Connect the DC Bus input connector (CON1) to the high voltage supply (400V DC), and the load to the inverter output (CON2)



8. Use the GUI or the on-board button SW1 to control the inverter on/off.

6.2 System Test

After the system is set up, the high voltage DC bus can be applied to the inverter, and the IGBT in full bridge connection will be switched in SPWM. The **Figure 6-2** shows the waveforms of the 120VAC/60Hz output voltage, current, and the gate drive signal of one IGBT. The input is set at 380V DC and the load is 50Ω resistive load. From the oscilloscope, the RMS of the output AC current is 2.4A.



Figure 6-2 Output of the Inverter and the Driver waveform

Since the Fly-Buck power supply has the advantage of the primary side regulation and thus good line regulation, the +24V auxiliary power doesn't need to be tightly regulated. While the inverter is operating, the +24V input can be varied +/-20%, and it won't affect the bias voltage level and all the drivers still operate stably. The **Figure 6-3** and **Figure 6-4** are the IGBT gate-to-emitter voltage (Vge) waveforms of one arm of the IGBT bridge captured at different Vin to the Fly-Buck supply (the Ch1 is the low side IGBT Vge, while the Ch3 is the high side IGBT Vge). It can be seen that the Vge switching remains almost unaffected by the change of the input voltage. The Δ Vge from +16V to -9V is kept at 25V, and the dead time is also unchanged. As a comparison, the original driver cards are also tested, and the results are shown in **Figure 6-5** and **Figure 6-6**. The difference is significant. There's no line/load regulation with the open-loop converter, and the Δ Vge varies from 24.5V to 30V even with a +/-10% Vin change. Also, the dead time is slightly affected.

The disturbance on the gate drive bias voltage is undesirable, as it will increase the switching loss and lower the system efficiency. Furthermore, for high power application, it could impact the system reliability and the IGBT life span, as the risk of false turn on and shoot through caused by the bias voltage deviation increases. Therefore, the Fly-Buck power supply for its robust performance is well suited for the IGBT gate drive bias.









Figure 6-4 Vge signal at 120% of Vin with Fly-Buck



Figure 6-5 Vge signal at 90% of Vin with Open-loop Converter





Figure 6-6 Vge signal at 110% of Vin with Open-loop Converter

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